



Sample &

Buv







SN74AHC1G32

SCLS317O-MARCH 1996-REVISED JULY 2014

# SN74AHC1G32 Single 2-Input Positive-OR Gate

#### 1 Features

- Operating Range of 2 V to 5.5 V
- Max t<sub>pd</sub> of 6.5 ns at 5 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±8-mA Output Drive at 5 V
- Schmitt-Trigger Action at All Inputs Makes the Circuit Tolerant for Slower Input Rise and Fall Time
- Latch-Up Performance Exceeds 250 mA Per JESD 17

#### 2 Applications

- **AV Receivers**
- Portable Audio Docks
- **Blu-ray Players and Home Theaters**
- MP3 Players and Recorders
- Personal Digital Assistants (PDAs)
- Power:
  - Telecom and Server AC DC Supply
  - Single Controllers
    - Analog
    - Digital
- Client and Enterprise Solid State Drives (SSDs)
- LCD and Digital TVs and High-Definition TVs (HDTVs)
- **Enterprise Tablets**
- Video Analytics Servers
- Wireless Headsets, Keyboards, and Mice

# 3 Description

The SN74AHC1G32 device is a single 2-input positive-OR gate. The device performs the Boolean function Y = A + B or  $Y = \overline{\overline{A} \cdot \overline{B}}$  in positive logic.

### **Device Information**<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)			
	SOT-23 (5)	2.90 mm × 1.60 mm			
SN74AHC1G32	SC70 (5)	2.00 mm × 1.25 mm			
	SOT (5)	1.60 mm × 1.20 mm			

(1) For all available packages, see the orderable addendum at the end of the datasheet.

# 4 Simplified Schematic





2

# **Table of Contents**

1	Feat	ures 1
2	Арр	lications 1
3	Des	cription 1
4	Sim	plified Schematic 1
5	Rev	ision History 2
6	Pin	Configuration and Functions
7	Spe	cifications 4
	7.1	Absolute Maximum Ratings 4
	7.2	Handling Ratings 4
	7.3	Recommended Operating Conditions 4
	7.4	Thermal Information 5
	7.5	Electrical Characteristics5
	7.6	Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} \dots 5$
	7.7	Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V \dots 5$
	7.8	Operating Characteristics 6
	7.9	Typical Characteristics 6
8	Para	ameter Measurement Information7

9	Deta	iled Description	8
	9.1	Overview	8
	9.2	Functional Block Diagram	8
	9.3	Feature Description	8
	9.4	Device Functional Modes	8
10	Арр	lication and Implementation	9
	10.1	Application Information	9
	10.2	Typical Application	9
11	Pow	ver Supply Recommendations 1	0
12	Lay	out1	0
	12.1	Layout Guidelines1	0
	12.2	Layout Example 1	0
13	Dev	ice and Documentation Support1	1
	13.1	Trademarks 1	1
	13.2	Electrostatic Discharge Caution 1	1
	13.3	Glossary1	1
14		hanical, Packaging, and Orderable mation 1	1

# 5 Revision History

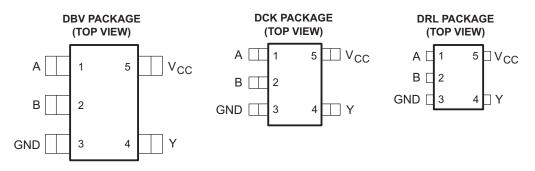
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	changes from Revision N (June 2005) to Revision O	Page
•	Updated document to new TI data sheet format	1
•	Removed Ordering Information table.	1
•	Added Applications.	1
•	Added Pin Functions table	3
•	Added Handling Ratings table.	4
•	Changed MAX ambient temperature in Recommended Operating Conditions table.	4
•	Added Thermal Information table.	5
•	Added –40 to 125°C to Electrical Characteristics table.	5
•	Added –55°C to 125°C to both Switching Characteristics tables.	5
•	Added Typical Characteristics.	

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# 6 Pin Configuration and Functions



See mechanical drawings for dimensions.

### Pin Functions for DBV, DCK, and DRL Packages

F	PIN	I/O	DESCRIPTION
NO.	NAME		DESCRIPTION
1	А	I	Input A
2	В	I	Input B
3	GND	—	Ground Pin
4	Y	0	Output Y
5	VCC	_	Power Pin

# 7 Specifications

## 7.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	7	V
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_{O} < 0$ or $V_{O} > V_{CC}$		±20	mA
Ι <sub>Ο</sub>	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA
	Continuous current through $V_{CC}$ or GND			±50	mA

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 7.2 Handling Ratings

			MIN	MAX	UNIT
T <sub>stg</sub>	Storage temperature rang	je	-60	150	°C
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	0	1500	V
V <sub>(ESD)</sub>		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	0	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		2	5.5	V	
		$V_{CC} = 2 V$	1.5			
V <sub>IH</sub>	High-level input voltage	$V_{CC} = 3 V$	2.1		V	
		$V_{CC} = 5.5 V$	3.85			
		$V_{CC} = 2 V$		0.5		
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V$		0.9	V	
		$V_{CC} = 5.5 V$		1.65		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		$V_{CC} = 2 V$		-50	μA	
I <sub>ОН</sub>	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		
		$V_{CC} = 5 V \pm 0.5 V$		-8	mA	
		$V_{CC} = 2 V$		50	μA	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	0	
		$V_{CC} = 5 V \pm 0.5 V$		8	mA	
A # / A \ .	Innut transition rise and fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	ns/V	
Δt/Δv	Input transition rise and fall rate	$V_{CC} = 5 V \pm 0.5 V$	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$			
T <sub>A</sub>	Operating free-air temperature		-40	125	°C	

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# 7.4 Thermal Information

	THERMAL METRIC <sup>(1)</sup>	DBV	DCK	DRL	
		5 PINS	5 PINS	5 PINS	UNIT
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	231.3	287.6	328.7	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	119.9	97.7	105.1	
$R_{\theta J B}$	Junction-to-board thermal resistance	60.6	65.0	150.3	°C/W
ΨJT	Junction-to-top characterization parameter	17.8	2.0	6.9	0.00
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	60.1	64.2	148.4	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

# 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDIT		N	T <sub>A</sub>	= 25°C				–40 TO 1	25°C	
PARAMETER	TEST CONDIT	IONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	2		1.9		1.9		
V <sub>OH</sub>	I <sub>OH</sub> = -50 μA		3 V	2.9	3		2.9		2.9		
			4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -4 \text{ mA}$		3 V	2.58			2.48		2.48		
	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		3.8			
		2 V			0.1		0.1		0.1		
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1		0.1		
V <sub>OL</sub>		4.5 V			0.1		0.1		0.1	v	
	$I_{OL} = 4 \text{ mA}$	3 V			0.36		0.44		0.44		
	I <sub>OL</sub> = 8 mA		4.5 V			0.36		0.44		0.44	
I	$V_{I} = 5.5 V \text{ or GND}$		0 V to 5.5 V			±0.1		±1		±1	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or GND,	$I_{O} = 0$	5.5 V			1		10		10	μA
Ci	$V_I = V_{CC} \text{ or } GND$		5 V		2	10		10		10	pF

# 7.6 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	то	LOAD	T <sub>A</sub>	= 25°C		-40	°C to 85°C	-40	°C to 12	5°C	UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	TYP MA	( MIN	Ι ΤΥΡ	MAX	UNIT	
t <sub>PLH</sub>	A or B	A	V	0 15 -		5.5		1	9.	5		10	
t <sub>PHL</sub>		ř	C <sub>L</sub> = 15 pF	pF 5.5 1	1	9.	5	l	10	ns			
t <sub>PLH</sub>	A or B	V	0 50 - 5		8		1	1	3		14		
t <sub>PHL</sub>		Ŷ	C <sub>L</sub> = 50 pF		8		1	1	3		14	ns	

# 7.7 Switching Characteristics, $V_{cc} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	то	LOAD	T <sub>A</sub> = 25°C		–40°C to 85°C			–40°C to 125°C			UNIT				
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN <sup>·</sup>	ТҮР	MAX	MIN	ТҮР	MAX	MIN	TYP	MAX				
t <sub>PLH</sub>	A or P	V	C <sub>1</sub> = 15 pF		3.8		1		6.5	1		7	ns			
t <sub>PHL</sub>	A or B	AUD	AUD	AUB	T			3.8		1		6.5	1		7	115
t <sub>PLH</sub>	A or B	V	C <sub>1</sub> = 50 pF		5.3		1		8.5	1		9.5	20			
t <sub>PHL</sub>		r	$O_L = 50 \text{ pr}$		5.3		1		8.5	1		9.5	ns			

### SN74AHC1G32

SCLS317O - MARCH 1996 - REVISED JULY 2014



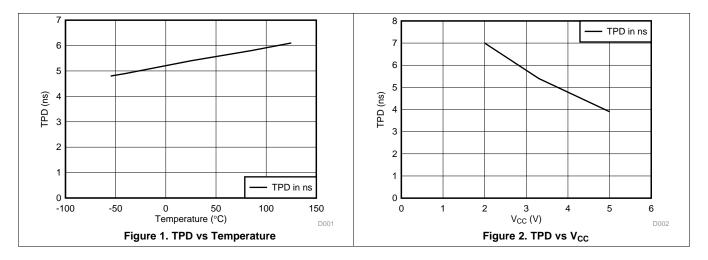
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# 7.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, \text{ } \text{T}_{\text{A}} = 25^{\circ}\text{C}$ 

	PARAMETER	TEST CO	TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	14	pF

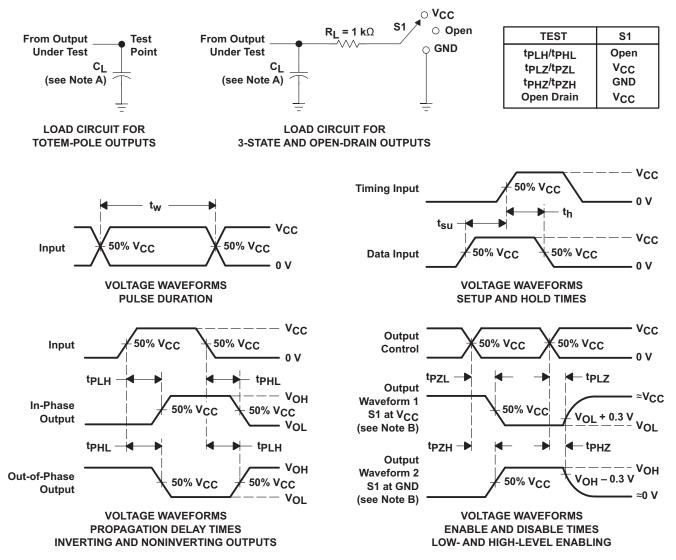
# 7.9 Typical Characteristics



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## 8 Parameter Measurement Information



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

### Figure 3. Load Circuit and Voltage Waveforms

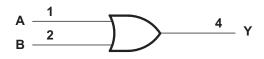


## 9 Detailed Description

## 9.1 Overview

The SN74AHC1G32 device is a single 2-input positive OR gate with low drive that produces slow rise and fall times. This reduces ringing on the output signal. The device also has Schmitt-trigger action that will allow for slower or noisier inputs. The input signals are high impedance when  $V_{CC} = 0$  V.

## 9.2 Functional Block Diagram



### 9.3 Feature Description

- Wide operating voltage
  - Operates from 2 V to 5.5 V
- Allows down voltage translation
  - Accepts input voltages to 5.5 V

### 9.4 Device Functional Modes

### **Table 1. Function Table**

INP	UTS	OUTPUT
Α	В	Y
Н	Х	Н
Х	Н	н
L	L	L



## **10** Application and Implementation

### **10.1** Application Information

The SN74AHC1G32 is a low-drive CMOS device that can be used for a multitude of bus-interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can except voltages to 5.5 V at any valid  $V_{CC}$  making it ideal for down translation.

## **10.2 Typical Application**

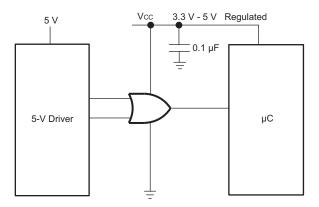


Figure 4. Specific Application Schematic

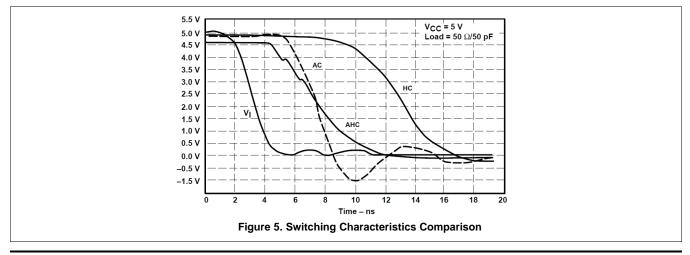
### 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

### 10.2.2 Detailed Design Procedure

- Recommended input conditions
  - Specified high and low levels. See (V<sub>IH</sub> and V<sub>IL</sub>) in the *Recommended Operating Conditions* table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid  $V_{CC}$
- Recommend output conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part
  - Outputs should not be pulled above  $V_{CC}$

### 10.2.3 Application Curves



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## **11** Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 µf is recommended; if there are multiple  $V_{CC}$  pins, then 0.01 µf or 0.022 µf is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 µf and a 1 µf are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

## 12 Layout

### 12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 6 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

## 12.2 Layout Example

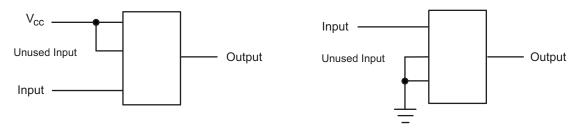


Figure 6. Layout Diagram



# **13** Device and Documentation Support

## 13.1 Trademarks

All trademarks are the property of their respective owners.

## **13.2 Electrostatic Discharge Caution**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



19-Mar-2015

# **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC1G32DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CUNIPDAU	Level-1-260C-UNLIM	-40 to 125	(A322 ~ A323 ~ A32G ~ A32J ~ A32L ~ A32S)	Samples
SN74AHC1G32DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	A32G	Samples
SN74AHC1G32DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	A32G	Samples
SN74AHC1G32DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(A323 ~ A32G ~ A32L ~ A32S)	Samples
SN74AHC1G32DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	A32G	Samples
SN74AHC1G32DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	A32G	Samples
SN74AHC1G32DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGJ ~ AGL ~ AGS)	Samples
SN74AHC1G32DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGJ ~ AGL ~ AGS)	Samples
SN74AHC1G32DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGJ ~ AGL ~ AGS)	Samples
SN74AHC1G32DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGL ~ AGS)	Samples
SN74AHC1G32DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGL ~ AGS)	Samples
SN74AHC1G32DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AG3 ~ AGG ~ AGL ~ AGS)	Samples
SN74AHC1G32DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AGB ~ AGS)	Samples
SN74AHC1G32DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(AGB ~ AGS)	Samples
SN74AHC1G32HDCK3	LIFEBUY	SC70	DCK	5		TBD	Call TI	Call TI	-40 to 85		

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



19-Mar-2015

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74AHC1G32 :

Automotive: SN74AHC1G32-Q1

NOTE: Qualified Version Definitions:

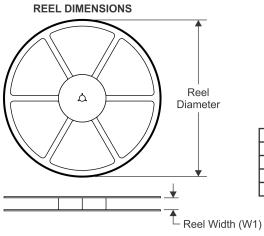
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

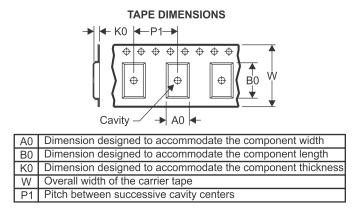
# PACKAGE MATERIALS INFORMATION

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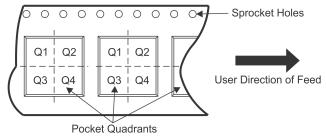
Texas Instruments

# TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



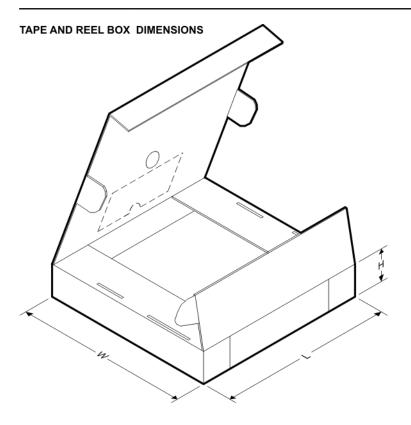
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC1G32DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74AHC1G32DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G32DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G32DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74AHC1G32DBVT	SOT-23	DBV	5	250	178.0	9.2	3.3	3.2	1.55	4.0	8.0	Q3
SN74AHC1G32DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G32DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G32DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHC1G32DCKR	SC70	DCK	5	3000	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AHC1G32DCKT	SC70	DCK	5	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AHC1G32DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHC1G32DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G32DRLR	SOT	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AHC1G32DRLR	SOT	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3

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# PACKAGE MATERIALS INFORMATION

23-Jan-2015



All dimensions are nominal								
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74AHC1G32DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0	
SN74AHC1G32DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0	
SN74AHC1G32DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0	
SN74AHC1G32DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0	
SN74AHC1G32DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0	
SN74AHC1G32DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0	
SN74AHC1G32DCKR	SC70	DCK	5	3000	180.0	180.0	18.0	
SN74AHC1G32DCKR	SC70	DCK	5	3000	180.0	180.0	18.0	
SN74AHC1G32DCKR	SC70	DCK	5	3000	205.0	200.0	33.0	
SN74AHC1G32DCKT	SC70	DCK	5	250	205.0	200.0	33.0	
SN74AHC1G32DCKT	SC70	DCK	5	250	180.0	180.0	18.0	
SN74AHC1G32DCKT	SC70	DCK	5	250	180.0	180.0	18.0	
SN74AHC1G32DRLR	SOT	DRL	5	4000	202.0	201.0	28.0	
SN74AHC1G32DRLR	SOT	DRL	5	4000	184.0	184.0	19.0	

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters. A.
  - This drawing is subject to change without notice. Β.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
  - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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